

Negative Fixed 5V Voltage Regulator in bare die form

Rev 1.0 19/04/19

Description

The 7905 5V fixed 3-terminal negative voltage regulator delivers up to 1.5A of output current with adequate heat-sinking. The device is equipped with internal limiting, safe-area compensation + thermal shutdown features for overload immunity. The 7905 can be used with external components to obtain adjustable voltages or currents & can also be used as the power-pass element in precision high-current voltage regulators. No external components are needed other than to enhance performance or increase design flexibility.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection.
- "H" MIL-STD-883 /2010B Visual Inspection
 + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K_AT

LAT = Lot Acceptance Test.

For further information on LAT places flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

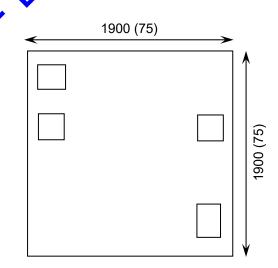
Supply Formats:

- Defaut Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Tape & Reel On request
- In Metal or Ceramic package On request

Features:

- ±5% V_{OUT} tolerance over entire temperature range
- Greater than 1A output current capability
- Internal thermal overload processing
- Internal short-circuit current imit
- Output capacitor not essential for stability
- Full military te npenature range
- Positive voltage complement is 7805

Die Qimensions in µm (mils)



Mechanical Specification

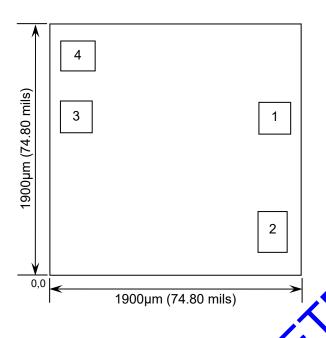
Die Size (Unsawn)	1900 x1900 75 x 75	μm mils	
Minimum Bond Pad Size	230 x 230 9.05 x 9.05	μm mils	
Die Thickness	280 (±20) 11.02 (±0.79)	μm mils	
Top Metal Composition	Al 1%Si 1.1μm		
Back Metal Composition	Ti/Ni/Ag 1.2 μm		





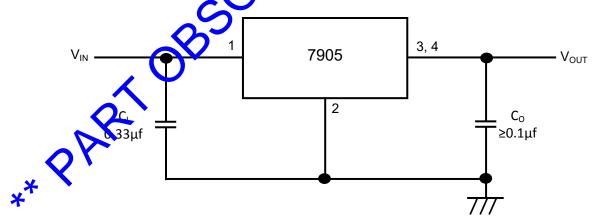
Rev 1.0 19/04/19

Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
FAD	1 UNCTION	X	Y		
1	V _{IN}	1.575	1.074		
2	GNV	1.572	0.188		
3	V _{OU}	0.088	1.059		
4	V _{OUT}	0.088	1.553		
CONNECT CHIP BACK TO V _{II}					

Typical Application



 $C_{\rm l}$ is required if the regulator is located an appreciable distance from power supply filter. $C_{\rm 0}$ is not required for stability; however it does improve transient response. For optimum stability and transient response locate $C_{\rm l}$ $C_{\rm 0}$ as close as possible to the regulator. A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.





Rev 1.0 19/04/19

Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UNI		
Input Voltage	V _{IN}	-35	V		
Power Dissipation ¹	P _D	Internally Limited	W		
Operating Temperature Range	-	-55 to 150	°C		
Maximum Junction Temperature	T _J	150	°C		
Storage Temperature	T _{STG}	-65 to 150	°C		

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V _{IN}		-25	V
Output Current	Гоит		1.5	A
Operating Temperature Range	TJ	-55	125	°C

DC Electrical Characteristics, V_I =-10V, I_{QUT} = 300mA,C_I=0.33μF, C_O=0.1μf, T_{MIN}≤T_J≤T_{MAX}(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage	V _{OUT}	= 25 °C	-4.80	-5.00	-5.20	V
		5mA ≤ 1 _{OUT} ≤ 1A, -7V ≥ V ≥ 20V, P _D ≤ 15 Watts	-4.75	-5.00	-5.25	
	ΔV _{OUT}	-7 / -25V,I _{OUT} =0.1A,T _J = 25°C	-	7	50	mV
Line Regulation		$-V \ge I_{IN} \ge -12V, I_{OUT} = 0.1A, T_{J} = 25^{\circ}C$	-	2	25	
		$V \ge V_{IN} \ge -25V, I_{OUT} = 0.5A, T_{J} = 25^{\circ}C$	-	35	100	
		$-8V \ge V_{IN} \ge -12V, I_{OUT} = 0.5A, T_{J} = 25^{\circ}C$	-	8	50	
Load Regulation	V _{OU}	$5\text{mA} \le I_{\text{OUT}} \le 1.5\text{A}, T_{\text{J}} = 25^{\circ}\text{C}$	-	11	100	
		250 mA $\leq I_{OUT} \leq 750$ mA, $T_{J} = 25$ °C	-	4	50	
Input Bias Current	I _B		-	4.3	7.8	mA
Input Bias Current	Δl_{B}	-7.5V ≥ V _{IN} ≥ -25V	-	-	1.3	mA
Change	ΔiB	5mA ≤ I _{OUT} ≤ 1.5A	-	-	0.5	111/-4
Output Noise Voltage	V _n	10Hz ≤ f ≤ 100KHz, T _J = 25°C	-	40	-	μV/V _{OUT}
Ripple Rejection	RR	I _{OUT} = 20mA, f = 120Hz,	-	70	-	dB
Dropout Voltage	$V_{IN} - V_{OUT}$	I _{OUT} = 1A, T _J = 25°C	-	2	-	V
Peak Output Current	I _{MAX}	T _J = 25°C	-	2.1	-	Α
Avg. Output Voltage Temp. Coefficient	TCV _{OUT}	I _{OUT} = 5mA, 0°C ≤ T _J ≤ +125°C	-	-1.0	-	mV/°C

^{1.} Results in die form are dependent on die attach and assembly method. Max power dissipation is internally limited by the die.









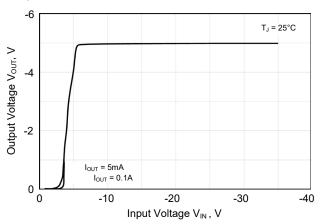


Figure 1 – Dropout Characteristics

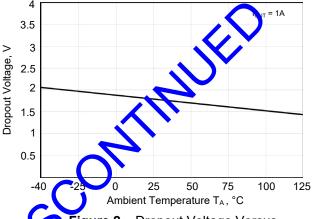


Figure 2 – Dropout Voltage Versus Temperature

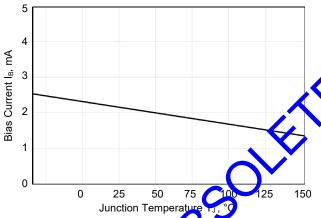


Figure 3 – Bias Cyr.er t Versus

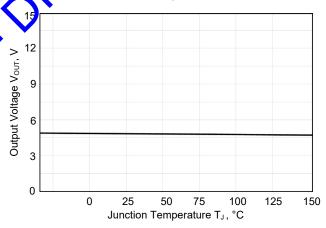


Figure 4 – Output Voltage Versus Temperature

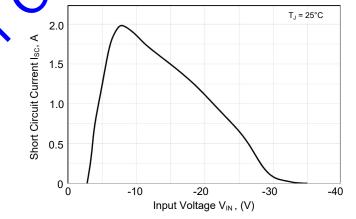


Figure 5 – Short-Circuit Current Versus Input Voltage





Rev 1.0 19/04/19

ER: The Porting

DISCEAIMER: The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Silicon Supplies Ltd hereby disclaims any and all warranties and liabilities of any kind.

LIFE SUPPORT POLICY: Silicon Supplies Ltd components may be used in life support devices or systems only with the express written approval of Silicon Supplies Ltd, if a failure of such components can reasonably be expected to cause the failure of that life support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

